

## CRYSTAL OSCILLATOR SPXO

# SG-615 series SG-531 / SG-51 series

- Frequency range : 1.025 MHz to 135 MHz
- Supply voltage : 3.3 V / 5.0 V
- Function : Output enable(OE) or Standby( $\overline{ST}$ )
- Pin compatible with full-size metal can. (SG-51 series)
- Pin compatible with half-size metal can. (SG-531 series)



Product Number (please contact us)

SG-615 : Q33615xx1xxx00

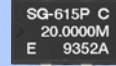
SG-531 : Q32531xx1xxx00

SG-51 : Q32510xx1xxx00



Actual size

SG-615



SG-531



SG-51



### Specifications (characteristics)

Item	Symbol	Specifications		Remarks
		SG-615P SG-531P SG-51P	SG-615PTJ SG-531PTJ SG-51PTJ	
Output frequency range	$f_0$	1.025 MHz to 26 MHz	26.001 MHz to 66.667 MHz	.
Supply voltage	$V_{CC}$	5.0 V $\pm$ 0.5 V		
Temperature range	Storage temperature $T_{stg}$	-55 °C to +125 °C		Store as bare product after unpacking
	Operating temperature $T_{use}$	-20 °C to +70 °C		
Frequency tolerance	$f_{tol}$	B: $\pm 50 \times 10^{-6}$ , C: $\pm 100 \times 10^{-6}$		-20 °C to +70 °C *1
Current consumption	$I_{CC}$	23 mA Max.	35 mA Max.	No load condition
Disable current	$I_{dis}$	12 mA Max.	28 mA Max.	OE=GND
Symmetry	SYM	40 % to 60 %	—	CMOS load:50 % $V_{CC}$ level
		40 % to 60 %	45 % to 55 %	TTL load: 1.4 V level
High output voltage	$V_{OH}$	$V_{CC}$ -0.4 V Min.	2.4 V Min.	$I_{OH}$ =-400 $\mu$ A
Low output voltage	$V_{OL}$	0.4 V Max.		$I_{OL}$ =16 mA(P)/ 8 mA(PTJ)
Output load condition (TTL)	$L_{TTL}$	10 TTL Max.	5 TTL Max.	$L_{CMOS} \leq 15$ pF
Output load condition (CMOS)	$L_{CMOS}$	50 pF Max.	—	
Output enable / disable input voltage	$V_{IH}$	2.0 V Min.	3.5 V Min.	$I_{IH}$ = 1 $\mu$ A Max. (OE= $V_{CC}$ )
	$V_{IL}$	0.8 V Max.	1.5 V Max.	$I_{IL}$ = -100 $\mu$ A Min. (OE=GND), PTJ: $I_{IL}$ = -500 $\mu$ A Min.(OE=GND)
Rise time / Fall time	$t_r / t_f$	8 ns Max.	—	CMOS load:20 % $V_{CC}$ to 80 % $V_{CC}$ level
		8 ns Max.	5 ns Max.	TTL load:0.4 V to 2.4 V level
Start-up time	$t_{str}$	4 ms Max.	10 ms Max.	Time at minimum supply voltage to be 0 s
Frequency aging	$f_{aging}$	$\pm 5 \times 10^{-6}$ / year Max.		+25 °C, $V_{CC}$ =5.0 V, First year

\*1 "B" tolerance will be available up to 55 MHz.

### Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		SG-615PCG SG-531PCG	SG-615SCG SG-531SCG	SG-615PCN	
Output frequency range	$f_0$	1.500 MHz to 26.000 MHz		26.001 MHz to 66.667 MHz	
Supply voltage	$V_{CC}$	2.7 V to 3.6 V		3.0 V to 3.6 V	
Temperature range	Storage temperature $T_{stg}$	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature $T_{use}$	-40 °C to +85 °C			
Frequency tolerance	$f_{tol}$	B: $\pm 50 \times 10^{-6}$ C: $\pm 100 \times 10^{-6}$ M: $\pm 100 \times 10^{-6}$		-20 °C to +70 °C -40 °C to +85 °C	
Current consumption	$I_{CC}$	12 mA Max.		20 mA Max.	No load condition
Disable current	$I_{dis}$	10 mA Max.	—	10 mA Max.	OE=GND (PCG,PCN)
Stand-by current	$I_{std}$	—	50 $\mu$ A Max.	—	$\overline{ST}$ =GND (SCG)
Symmetry	SYM	45 % to 55 %			50 % $V_{CC}$ level, $L_{CMOS}$ =Max.
High output voltage	$V_{OH}$	$V_{CC}$ -0.4 V Min.		$V_{CC}$ -0.4 V Min.	$I_{OH}$ =-8 mA
Low output voltage	$V_{OL}$	0.4 V Max.		0.4 V Max.	$I_{OL}$ = 8 mA
Output load condition	$L_{CMOS}$	25 pF Max.		15 pF Max.	
Output enable / disable input voltage	$V_{IH}$	70 % $V_{CC}$ Min.		70 % $V_{CC}$ Min.	OE Terminal or $\overline{ST}$ Terminal
	$V_{IL}$	20 % $V_{CC}$ Max.		30 % $V_{CC}$ Max.	
Rise time / Fall time	$t_r / t_f$	4 ns Max.			20 % $V_{CC}$ to 80 % $V_{CC}$ level, $L_{CMOS} \leq$ Max.
Start-up time	$t_{str}$	12 ms Max.		10 ms Max.	$t=0$ at 90% $V_{CC}$
Frequency aging	$f_{aging}$	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, $V_{CC}$ =3.3 V, First year



Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		SG-615PTW / STW SG-531PTW / STW	SG-615PHW / SHW SG-531PHW / SHW	SG-615PCW / SCW SG-531PCW / SCW	
Output frequency range	f <sub>0</sub>	55.001 MHz to 135.000 MHz		26.001 MHz to 135.000 MHz	
Supply voltage	V <sub>cc</sub>	5.0 V ±0.5 V		3.3 V ±0.3 V	
Temperature range	Storage temperature	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature	-20 °C to +70 °C		-40 °C to +85 °C	
Frequency tolerance	f <sub>tol</sub>	B: ±50 × 10 <sup>-6</sup> , C: ±100 × 10 <sup>-6</sup>		M: ±100 × 10 <sup>-6</sup>	-20 °C to +70 °C *1
		—		—	-40 °C to +85 °C
Current consumption	I <sub>cc</sub>	45 mA Max.		28 mA Max.	No load condition( Max. frequency range )
Disable current	I <sub>dis</sub>	30 mA Max.		16 mA Max.	OE=GND (PTW,PHW,PCW)
Stand-by current	I <sub>std</sub>	50 µA Max.		—	ST=GND (STW,SHW,SCW)
Symmetry	SYM	—		40 % to 60 %	50 % V <sub>cc</sub> level, L <sub>CMOS</sub> =Max.
		40 % to 60 %		—	—
High output voltage	V <sub>OH</sub>	V <sub>cc</sub> -0.4 V Min.			I <sub>OH</sub> =-16 mA(PTW,STW,PHW,SHW), -8 mA(PCW,SCW)
Low output voltage	V <sub>OL</sub>	0.4 V Max.			I <sub>OL</sub> = 16 mA(PTW,STW,PHW,SHW), 8 mA(PCW,SCW)
Output load condition (TTL)	L <sub>TTL</sub>	5 TTL Max.	—	—	f <sub>0</sub> ≤ 90 MHz, Max.supply voltage
Output load condition (CMOS)	L <sub>CMOS</sub>	15 pF Max.			Max.frequency, Max.supply voltage
Output enable / disable input voltage	V <sub>IH</sub>	2.0 V Min.		70 % V <sub>cc</sub> Min.	OE Terminal or ST Terminal
	V <sub>IL</sub>	0.8 V Max.		20 % V <sub>cc</sub> Max.	
Rise time / Fall time	t <sub>r</sub> / t <sub>f</sub>	—		4 ns Max.	20 % V <sub>cc</sub> to 80 % V <sub>cc</sub> level, L <sub>CMOS</sub> ≤ Max.
		4 ns Max.		—	
Start-up time	t <sub>str</sub>	10 ms Max..			Time at minimum supply voltage to be 0 s
Frequency aging	f <sub>aging</sub>	±5 × 10 <sup>-6</sup> / year Max.			+25 °C, V <sub>cc</sub> =5.0 V / 3.3 V, First year

\*1 "C" tolerance : f<sub>0</sub> ≥66.667 MHz(PTW,STW,PHW,SHW )

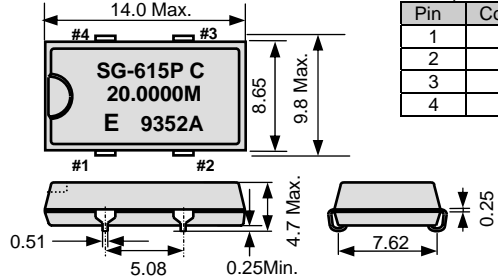
External dimensions

(Unit:mm)

Footprint (Recommended)

(Unit:mm)

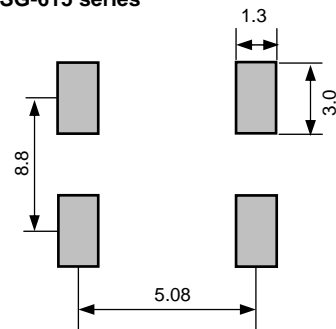
● SG-615 series



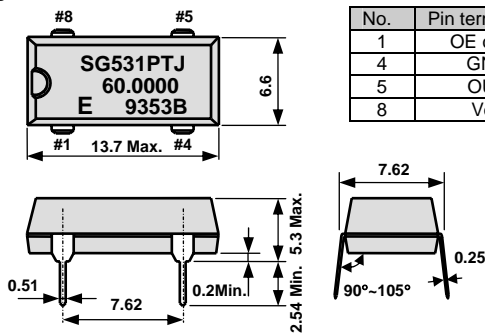
Pin map

Pin	Connection
1	OE or ST
2	GND
3	OUT
4	V <sub>cc</sub>

● SG-615 series

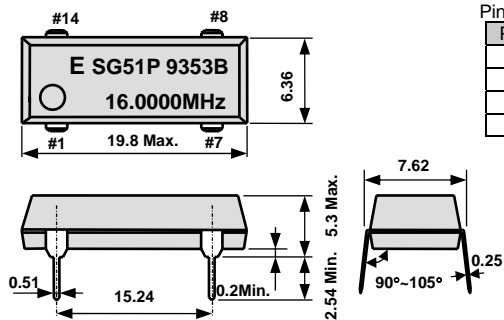


● SG-531 series



No.	Pin terminal
1	OE or ST
4	GND
5	OUT
8	V <sub>cc</sub>

● SG-51 series



Pin map

Pin	Connection
1	OE or ST
7	GND
8	OUT
14	V <sub>cc</sub>

Note.

OE pin (P,PTJ,PTW,PHW,PCW,PCN,PCG)  
OE pin = "H" or "open" : Specified frequency output.  
OE pin = "L" : Output is high impedance.

ST pin (STW, SHW, SCW,SCG)  
ST pin = "H" or "open" : Specified frequency output.  
ST pin = "L" : Output is low level  
(weak pull - down), oscillation stops.

To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between V<sub>cc</sub> - GND).

# “QMEMS” EPSON TOYOCOM

In order to meet customer needs in a rapidly advancing digital, broadband and ubiquitous society, we are committed to offering products that are one step ahead of the market and a rank above the rest in quality. To achieve our goals, we follow a “3D (three device) strategy” designed to drive both horizontal and vertical growth. We will to grow our three device categories of “Timing Devices”, “Sensing Devices” and “Optical Devices”, and expand vertical growth through a combination of products from these categories.

A Quartz MEMS is any high added value quartz device that exploits the characteristics of quartz crystal material but that is produced using MEMS (micro-electro-mechanical system) processing technology.

Market needs are advancing faster than previously imagined toward smaller, more stable crystal products, but we will stay ahead of the curve by rolling out products that exceed market speed and quality requirements. We want to further accelerate the 3D strategy by QMEMS.

Quartz devices have become crucial in the network environment where products are increasingly intended for broadband, ubiquitous applications

and where various types of terminals can transfer information almost immediately via LAN and WAN on a global scale. Epson Toyocom Corporation addresses every single aspect within a network environment. The new corporation offers “Digital Convergence” solutions to problems arising with products for consumer use, such as, core network systems and automotive systems.



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At Epson Toyocom, all environmental initiatives operate under the Plan-Do-Check-Action(PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.




## WORKING FOR HIGH QUALITY

In order provide high quality and reliable products and services than meet customer needs,

Epson Toyocom made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired ISO/TS 16949 certification that is requested strongly by major automotive manufacturers as standard.

ISO/TS16949 is the international standard that added the sector-specific supplemental requirements for automotive industry based on ISO9001.

### ► Explanation of the mark that are using it for the catalog

	► Pb free.
	► Complies with EU RoHS directive. *About the products without the Pb-free mark. Contains Pb in products exempted by EU RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.)
	► The products have been designed for high reliability applications such as Automotive.

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